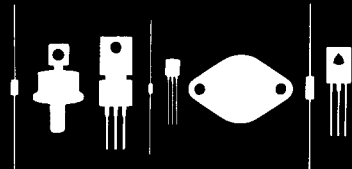


Central
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145 Adams Avenue
Hauppauge, New York 11788



2N1479
2N1480
2N1481
2N1482

NPN SILICON TRANSISTOR

JEDEC TO-39 CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N1479 series types are silicon NPN transistors manufactured by the epitaxial planar process, mounted in a hermetically sealed metal case designed for switching and amplifier applications.

MAXIMUM RATINGS ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL	2N1479 2N1481	2N1480 2N1482	UNIT
Collector-Base Voltage	V _{CB0}	60	100	V
Collector-Emitter Voltage	V _{CEV}	60	100	V
Collector-Emitter Voltage	V _{CEO}	40	55	V
Emitter-Base Voltage	V _{EB0}	6.0	6.0	V
Collector Current	I _C	1.5	1.5	A
Base Current	I _B	1.0	1.0	A
Power Dissipation	P _D	5.0	5.0	W
Operating and Storage Junction Temperature	T _J , T _{STG}	-65 TO +200		°C
Thermal Resistance	θ _{JC}	35		°C/W

ELECTRICAL CHARACTERISTICS ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	2N1479		2N1480		2N1481		2N1482		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
I _{CB0}	V _{CB} =30V		10		10		10		10	μA
I _{CB0}	V _{CB} =30V, T _C =150°C		500		500		500		500	μA
I _{EB0}	V _{EB} =6.0V		10		10		10		10	μA
V _{CEV}	V _{EB} =1.5V, I _C =0.25mA	60		100		60		100		V
V _{CEO}	I _C =50mA	40		55		40		55		V
V _{CE(SAT)}	I _C =200mA, I _B =10mA		-		-		1.4		1.4	V
V _{CE(SAT)}	I _C =200mA, I _B =20mA		1.4		1.4		-		-	V
V _{BE(ON)}	V _{CE} =4.0V, I _C =200mA		3.0		3.0		3.0		3.0	V
h _{FE}	V _{CE} =4.0V, I _C =200mA	20	60	20	60	35	100	35	100	
h _{fe}	V _{CE} =4.0V, I _C =5.0mA		50 TYP		50 TYP		50 TYP		50 TYP	
t _{ON}	I _C =200mA, I _{B1} =20mA, I _{B2} =85mA		1.2 TYP		1.2 TYP		1.2 TYP		1.2 TYP	μs
t _{OFF}	I _C =200mA, I _{B1} =20mA, I _{B2} =85mA		1.6 TYP		1.6 TYP		1.6 TYP		1.6 TYP	μs
C _{ob}	V _{CB} =40V		150 TYP		150 TYP		150 TYP		150 TYP	pF
f _{αB}	V _{CB} =28V, I _C =5.0mA		1.5 TYP		1.5 TYP		1.5 TYP		1.5 TYP	MHz

**Central™
Semiconductor Corp.**

145 Adams Avenue
Hauppauge, NY 11788 USA
Tel: (631) 435-1110 • Fax: (631) 435-1824
www.centrasemi.com

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp.
145 Adams Avenue
Hauppauge, NY 11788 USA
Main Tel: (631) 435-1110
Main Fax: (631) 435-1824
Support Team Fax: (631) 435-3388
www.centrasemi.com

Worldwide Field Representatives:
www.centrasemi.com/wwreps

Worldwide Distributors:
www.centrasemi.com/wwdistributors

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